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A Single-Inductor Triple-Output Buck-Boost Converter with Output Ripple Control for Wearable Devices

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Introduction

(SITO) triple-output single-input battery $\Box A$ management unit regulates triple output voltages for different back-end circuits.

Target input voltage: V_{BAT} = 2.8V - 4.8V

Target output voltage: $V_{O_1} = 1.2V, V_{O_2} = 1.8V, V_{O_3} = 3.3V$

System Architecture





proposed SITO battery management unit □The provides three different regulated outputs using a shared off-chip inductor and three off-chip capacitors.

The PSM controller decides which output channel needs to be powered according to the output voltage level.

Measurement Results

Comparison to recently reported works [5]

	JSSC 2011 [1]	TPEL 2016 [2]	ICECS 2018 [3]	TCAS-II 2019 [4]	This Work
Technology	45 nm CMOS	90 nm CMOS	180 nm CMOS	180 nm CMOS	180 nm BCD
Input voltage	2.8V~4.2V	1.8V~4.2V	3.4V~5V	3.2V ~ 4.8V	2.8V ~ 4V
# of output	1	1	2	3	3
Output voltage	0.4V~1.2V	0.9V~1.4V	3V / 2V	2V / 6V / -6V	1.2V / 1.8V / 2.8V~3.3V
Regulated mechanism	PFM+PWM	PFM	PSM	PSM	PSM
Inductance	10uH	4.7uH~10uH	4.7uH	4.7uH	1uH
Output capacitance	2uF	2.2uF~10uF	N/A	10uF	10uF
Output ripple	20mV	20mV	N/A	> 100mV	< 30mV of V _{OUT1} < 30mV of V _{OUT2} < 60mV of V _{OUT3}
Maximum output power	100mW	56mW	65mW	40mW	315mW
Peak efficiency	87.4%	86.2%	93.6%	82.9%	75.8%



The converter achieves maximum efficiency of 75.8% with an 1μ H inductor under V_{BAT}= 3.7V, I_{LOAD1,2,3} = 50mA [5].



Reference

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- [2] W. Fu, S. T. Tan, M. Radhakrishnan, R. Byrd, and A. A. Fayed, "A DCM-only buck regulator with hysteretic-assisted adaptive minimum-on-time control for low-power microcontrollers," IEEE Trans.

DAOT generator is used to maintain output power range and output ripple with different V_{BAT}



 \Box The low-V_{BAT} control shorts V_{BAT} and V_{OUT3} together to save energy when VBAT is lower than the third output channel (3.3V).

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